

#### Positive Fixed 5V Voltage Regulator in bare die form

## Description

The 78L05 is a 5V fixed 3-terminal voltage regulator delivering up to 100mA of output current and equipped with internal limiting + thermal shutdown features for overload immunity. Implementing this device at pointof-source removes the complexity of single point regulation methods with reduced noise. Used in replacement of a Zener diode/resistor combination, the device improves output impedance by x2 order of magnitude and delivers lower bias current with lower noise. The 78L05 can also be used with power-pass elements to make high-current voltage regulators.

# **Ordering Information**

The following part suffixes apply:

- No suffix MIL-STD-883 /2010B Visual Inspection
- "H" MIL-STD-883 /2010B Visual Inspection + MIL-PRF-38534 Class H LAT
- "K" MIL-STD-883 /2010A Visual Inspection (Space) + MIL-PRF-38534 Class K LAT

LAT = Lot Acceptance Test.

For further information on LAT process flows see below.

www.siliconsupplies.com\quality\bare-die-lot-qualification

## Supply Formats:

- Default Die in Waffle Pack (400 per tray capacity)
- Sawn Wafer on Tape On request
- Unsawn Wafer On request
- With Ti/Ni/Ag Back Metal On request
- In Metal or Ceramic package On request

### Features:

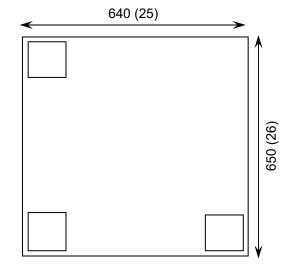
• ±5% V<sub>OUT</sub> tolerance over entire temperature range

Rev 1.0

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- 100mA Output Current
- Internal thermal overload protection
- Internal short circuit current limit
- Full military temperature range
- Industry smallest die size
- Negative Voltage complement is 79L05

## Die Dimensions in µm (mils)



# **Mechanical Specification**

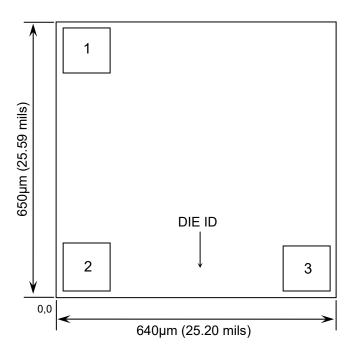
Die Size (Unsawn)	640 x 650 25.20 x 25.59	μm mils	
Minimum Bond Pad Size	90 x 90 3.54x 3.54	μm mils	
Die Thickness	280 (±20) 11 (±0.8)	µm mils	
Top Metal Composition	Al 1%Si 1.4µm		
Back Metal Composition	N/A – Bare Si		





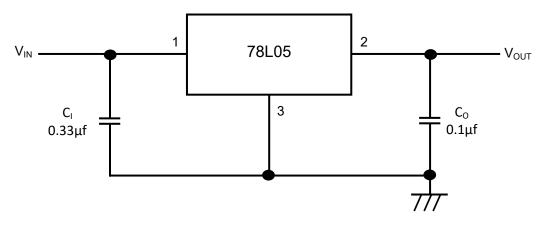
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## Pad Layout and Functions



PAD	FUNCTION	COORDINATES (µm)			
		X	Y		
1	V <sub>IN</sub>	57	490.5		
2	V <sub>OUT</sub>	58.5	61		
3	GND	503	61		
CONNECT CHIP BACK TO GND					

## **Typical Application**



 $C_l$  is required if the regulator is located an appreciable distance from power supply filter.  $C_o$  is not required for stability; however it does improve transient response. For optimum stability and transient response locate  $C_l C_o$  as close as possible to the regulator.





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### Absolute Maximum Ratings

5						
PARAMETER	ER SYMBOL		UNIT			
Input Voltage	V <sub>IN</sub>	30	V			
Power Dissipation <sup>1</sup>	PD	620	mW			
Operating Temperature Range	-	-55 to 125	°C			
Maximum Junction Temperature	TJ	150	°C			
Storage Temperature	T <sub>STG</sub>	-65 to 150	°C			

### **Recommened Operating Conditions**

PARAMETER	SYMBOL	MIN	MAX	UNIT
Input Voltage	V <sub>IN</sub>	7	20	V
Output Current	I <sub>OUT</sub>	-	100	mA
Operating Temperature Range	TJ	-55	125	°C

### DC Electrical Characteristics, V<sub>I</sub> = 10V, I<sub>OUT</sub>=40mA,C<sub>I</sub>=0.33µF, C<sub>O</sub>=0.1µf, 0°C<T<sub>J</sub><+125°C(unless noted otherwise)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Output Voltage	V <sub>OUT</sub>	$T_J = 25^{\circ}C$ , $1mA \le I_O \le 70mA$	4.80	5.00	5.20	V
		$1\text{mA} \le I_{\text{OUT}} \le 40\text{mA}, 7\text{V} \le \text{V}_{\text{IN}} \le 20\text{V}$	4.75	5.00	5.25	
		$1\text{mA} \le I_{\text{OUT}} \le 70\text{mA}, V_{\text{IN}} = 10\text{V}$	4.75	5.00	5.25	
Line Regulation $\Delta V_{OUT}$	$7V \le V_{IN} \le 20V, T_J = 25^{\circ}C, I_O = 40mA$	-	13	135		
	<b>Av</b> 001	$8V \le V_{IN} \le 20V, T_J = 25^{\circ}C, I_O = 40mA$	-	9	90	mV
Load Regulation	ΔV <sub>OUT</sub>	$1\text{mA} \le I_{\text{OUT}} \le 100\text{mA}, T_{\text{J}} = 25^{\circ}\text{C}$	-	15	54	
	<b>Av</b> 001	$1\text{mA} \le I_{\text{OUT}} \le 40\text{mA}, T_{\text{J}} = 25^{\circ}\text{C}$	-	8	28	
Input Bias Current	1-	T <sub>J</sub> = 25°C	-	1.9	5.0	mA
	чВ	T <sub>J</sub> = 125°C	-	1.8	4.5	
Input Bias Current		$8V \le V_{IN} \le 20V$	-	-	1.3	mA
Change $\Delta I_B$	ΔIB	$ImA \le I_{OUT} \le 40mA$	-	-	0.09	
Output Noise Voltage	e <sub>N</sub>	10Hz ≤ f ≤ 100KHz, T <sub>A</sub> = 25°C	-	42	-	μV <sub>RMS</sub>
Ripple Rejection	RR	$f = 120Hz, 8V \le V_{IN} \le 18V, T_J = 25^{\circ}C$	43	64	-	dB
Dropout Voltage	VD	V <sub>IN</sub> -V <sub>OUT</sub>	-	1.7	-	V

**1.** Value measured in TO-92 package applicable only for DC power dissipation permitted by absolute maximum ratings. Results in die form are dependent on die attach and assembly method.





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